

600 nA, Non-Unity Gain Rail-to-Rail Input/Output Op Amps

Features

- Low Quiescent Current: 600 nA/Amplifier (typ.)
- Stable for gains of 10 V/V or higher
- Rail-to-Rail Input: -0.3V (min.) to V_{DD} + 0.3V (max.)
- Rail-to-Rail Output:
- V_{SS}+10 mV (min.) to V_{DD}-10 mV (max.)
- Gain Bandwidth Product: 100 kHz (typ.)
- Wide Supply Voltage Range: 1.4V to 5.5V (max.)
- · Available in Single, Dual and Quad
- Chip Select (CS) with MCP6143

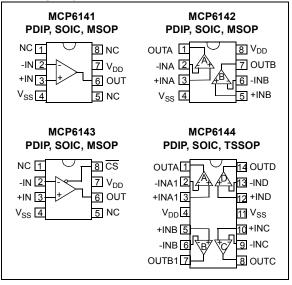
Applications

- Toll Booth Tags
- Wearable Products
- Temperature Measurement
- Battery-Powered

Available Tools

- · Spice macro models (at www.microchip.com)
- FilterLab[®] Software (at <u>www.microchip.com</u>)

Package Types



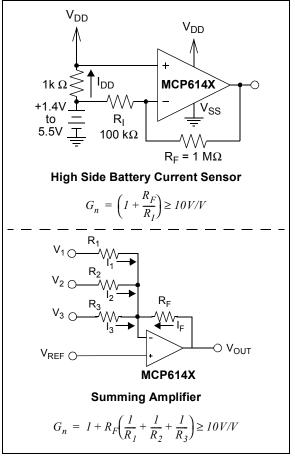
Description

The MCP6141/2/3/4 family of non-unity gain stable operational amplifiers (op amps) from Microchip Technology, Inc. operate with a single supply voltage as low as 1.4V, while drawing less than 1 μ A (max.) of quiescent current per amplifier. These devices are also designed to support rail-to-rail input and output swing.

The MCP6141/2/3/4 op amps have a gain bandwidth product of 100 kHz (typ.) and are stable for gains of 10 V/V or higher. This specification makes these devices appropriate for battery-powered applications where higher frequency responses from the amplifier are required.

The MCP6141/2/3/4 family of op amps are offered in single (MCP6141), single with a Chip Select (CS) feature (MCP6143), dual (MCP6142) and quad (MCP6144) configurations.

Typical Applications



1.0 ELECTRICAL CHARACTERISTICS

1.1 Maximum Ratings†

V _{DD} - V _{SS}	7.0V
All inputs and outputs	$V_{\rm SS}$ -0.3V to $V_{\rm DD}$ +0.3V
Difference Input voltage	V _{DD} - V _{SS}
Output Short Circuit Current	continuous
Current at Input Pins	±2 mA
Current at Output and Supply Pins	±30 mA
Storage temperature	65°C to +150°C
Junction Temperature, T _J	+150°C
ESD protection on all pins (HBM:MM).	≥4 kV:200 V

†Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

PIN FUNCTION TABLE

Name	Function
+IN/+INA/+INB/+INC/+IND	Non-inverting Inputs
-IN/-INA/-INB/-INC/-IND	Inverting Inputs
V _{DD}	Positive Power Supply
V _{SS}	Negative Power Supply
OUT/OUTA/OUTB/OUTC/OUTD	Outputs
CS	Chip Select
NC	No internal connection

DC ELECTRICAL	SPECIFICATIONS
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Electrical Characteristics: Unless otherwise indicated, all limits are specified for V _{DD} = +1.4V to +5.5V, V _{SS} = GND, T _A = 25°C,								
$V_{CM} = V_{DD}/2$, $R_L = 1 M\Omega$ to $V_{DD}/2$, and $V_{OUT} \sim V_{DD}/2$.								
_	-		_					

Parameters	Sym	Min	Тур	Max	Units	Conditions
Input Offset						V _{CM} = V _{SS}
Input Offset Voltage	V _{OS}	-3.0	_	+3.0	mV	
Drift with Temperature	$\Delta V_{OS} / \Delta T$	_	±1.5	_	μV/°C	T_A = -40°C to +85°C
Power Supply Rejection	PSRR	70	85	_	dB	
Input Bias Current and Impedance						
Input Bias Current	I _B	_	1.0	_	pА	
Input Bias Current Over-Temperature	Ι _Β	_	_	100	pА	T_A = -40°C to +85°C
Input Offset Current	I _{OS}	_	1.0	_	pА	
Common Mode Input Impedance	Z _{CM}	_	10 ¹³ 6	_	Ω pF	
Differential Input Impedance	Z _{DIFF}	_	10 ¹³ 6	_	Ω pF	
Common Mode	•					
Common-Mode Input Range	VCMR	V _{SS} - 0.3	_	V _{DD} + 0.3	V	
Common-Mode Rejection Ratio	CMRR	62	80	_	dB	V _{DD} = 5V, V _{CM} = -0.3V to 5.3V
		60	75	_	dB	V _{DD} = 5V, V _{CM} = 2.5V to 5.3V
		60	80	_	dB	V _{DD} = 5V, V _{CM} = -0.3V to 2.5V
Open Loop Gain						
DC Open Loop Gain (large signal)	A _{OL}	95	115	_	dB	R_L = 50 kΩ to V _{DD} /2, 100 mV < V _{OUT} < (V _{DD} - 100 mV)
Output						
Maximum Output Voltage Swing	V _{OL} , V _{OH}	V _{SS} + 10	_	V _{DD} - 10	mV	R_L = 50 k Ω to $V_{DD}/2$
Output Short Circuit Current	Ι _Ο	_	21	_	mA	V _{OUT} = 2.5V, V _{DD} = 5 V
Power Supply						
Supply Voltage	V _{DD}	1.4	_	5.5	V	
Quiescent Current per amplifier	I _O	0.3	0.6	1.0	μA	I _O = 0

AC ELECTRICAL SPECIFICATIONS

	Electrical Characteristics: Unless otherwise indicated, all limits are specified for V_{DD} = +5V, V_{SS} = GND, T_A = 25 °C,								
	$V_{CM} = V_{DD}/2$, $R_L = 1 M\Omega$ to $V_{DD}/2$, $C_L = 60 \text{ pF}$, and $V_{OUT} \sim V_{DD}/2$.								
Parameters Sym Min Typ Max Units Condit						Conditions			

Gain Bandwidth Product	GBWP	_	100	—	kHz	
Slew Rate	SR	_	24	—	V/ms	
Phase Margin	PM	_	60	—	0	G = +10
Input Voltage Noise	En		5.0	—	μVp-р	f = 0.1 Hz to 10 Hz
Input Voltage Noise Density	e _n	_	170	—	nV/√Hz	f = 1 kHz
Input Current Noise Density	i _n	_	0.6	—	fA/√Hz	f = 1 kHz

SPECIFICATIONS FOR MCP6143 CHIP SELECT FEATURE

Electrical Characteristics: Unless otherwise indicated, all limits are specified for V_{DD} = +1.4V to +5.5V, V_{SS} = GND, T_A = 25 °C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
CS Low Specifications								
CS Logic Threshold, Low	V _{IL}	V _{SS}	_	V _{SS} + 0.3	V	For entire V _{DD} range		
CS Input Current, Low	I _{CSL}	_	5.0	_	pА	$\overline{\text{CS}} = \text{V}_{\text{SS}}$		
CS High Specifications								
CS Logic Threshold, High	V _{IH}	V _{DD} - 0.3		V _{DD}	V	For entire V _{DD} range		
CS Input Current, High	I _{CSH}	_	5.0	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$		
CS Input High, GND Current	Ι _Q	_	20	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$		
Amplifier Output Leakage, $\overline{\text{CS}}$ High		_	20	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$		
Dynamic Specifications								
CS Low to Amplifier Output High Turn-on Time	t _{ON}	_	2.0	50	ms	$\overline{\text{CS}} \text{ low} = \text{V}_{\text{SS}} + 0.3 \text{V}, \text{ G} = +1 \text{ V/V}, \\ \text{V}_{\text{OUT}} = 0.9 \text{ V}_{\text{DD}}/2$		
$\overline{\text{CS}}$ High to Amplifier Output High Z	t _{OFF}	_	10	_	μs	$\overline{\text{CS}} \text{ high = V}_{\text{DD}} - 0.3 \text{V}, \text{ G} = +1 \text{ V/V}$ $\text{V}_{\text{OUT}} = 0.1 \text{ V}_{\text{DD}}/2$		
Hysteresis	V _{HYST}	_	0.6	_	V	V _{DD} = 5V		

TEMPERATURE SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, all limits are specified for V _{DD} = +1.4V to +5.5V, V _{SS} = GND.									
Parameters	Symbol	Min	Тур	Max	Units	Conditions			
Temperature Ranges									
Specified Temperature Range	T _A	-40	_	+85	°C				
Operating Temperature Range	T _A	-40	_	+125	°C	Note 1			
Storage Temperature Range	T _A	-65	_	+150	°C				
Thermal Package Resistances									
Thermal Resistance, 8L-PDIP	θ_{JA}	—	85	—	°C/W				
Thermal Resistance, 8L-SOIC	θ_{JA}	_	163	_	°C/W				
Thermal Resistance, 8L-MSOP	θ_{JA}	—	206	—	°C/W				
Thermal Resistance, 14L-PDIP	θ_{JA}	_	70	_	°C/W				
Thermal Resistance, 14L-SOIC	θ_{JA}	_	108	_	°C/W				
Thermal Resistance, 14L-TSSOP	θ_{JA}	_	100	_	°C/W				

Note 1: The MCP6141/2/3/4 family of op amps operates over this extended range, but with reduced performance.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.

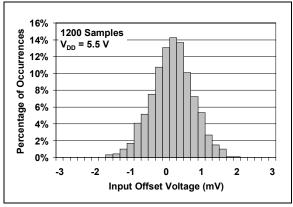


FIGURE 2-1: Histogram of Input Offset Voltage with $V_{DD} = 5.5V$.

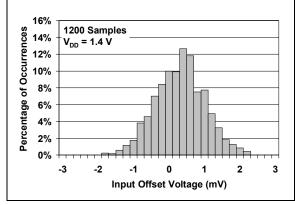


FIGURE 2-2: Histogram of Input Offset Voltage with $V_{DD} = 1.4V$.

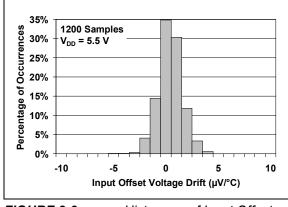


FIGURE 2-3: Histogram of Input Offset Voltage Drift with $V_{DD} = 5.5V$.

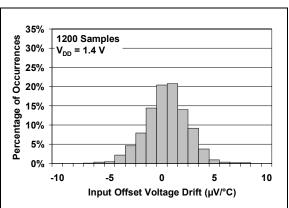


FIGURE 2-4: Histogram of Input Offset Voltage Drift with $V_{DD} = 1.4V$.

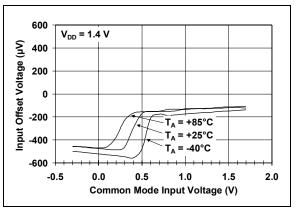


FIGURE 2-5: Input Offset Voltage vs. Common Mode Input Voltage vs. Temperature with $V_{DD} = 1.4V$.

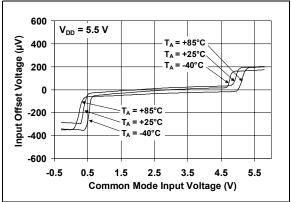


FIGURE 2-6: Input Offset Voltage vs. Common Mode Input Voltage vs. Temperature with $V_{DD} = 5.5V$.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.

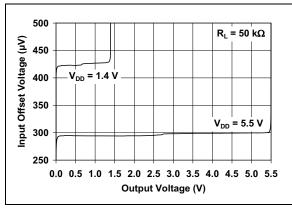


FIGURE 2-7:Input Offset Voltage vs.Output Voltage vs. Power Supply Voltage.

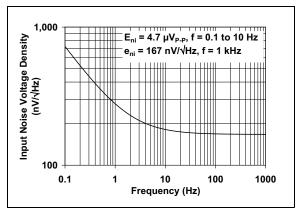


FIGURE 2-8: Input Noise Voltage Density vs. Frequency.

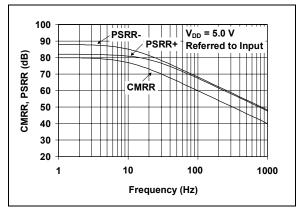


FIGURE 2-9: Common Mode Rejection Ratio, Power Supply Rejection Ratio vs. Frequency.

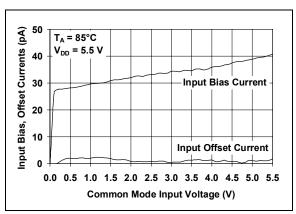


FIGURE 2-10: Input Bias, Offset Currents vs. Common Mode Input Voltage with Temperature = 85°C.

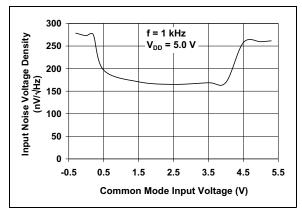


FIGURE 2-11: Input Noise Voltage Density vs. Common Mode Input Voltage.

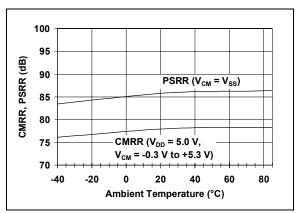
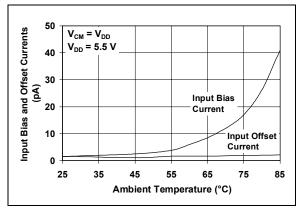


FIGURE 2-12: Common Mode Rejection Ratio, Power Supply Rejection Ratio vs. Ambient Temperature.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.





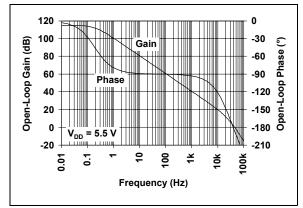


FIGURE 2-14: Open Loop Gain, Phase vs. Frequency with $V_{DD} = 5.5V$.

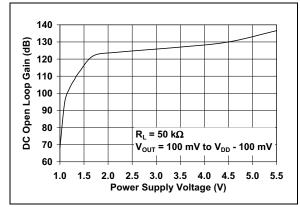


FIGURE 2-15: DC Open Loop Gain vs. Power Supply Voltage.

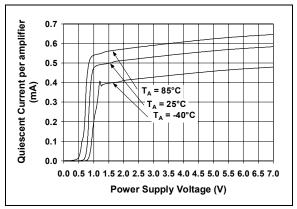


FIGURE 2-16: Quiescent Current Vs. Power Supply Voltage vs. Temperature.

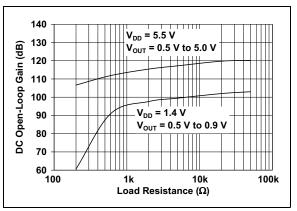


FIGURE 2-17: DC Open Loop Gain vs. Load Resistance vs. Power Supply Voltage.

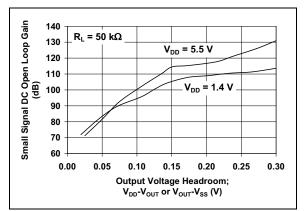


FIGURE 2-18: Small Signal DC Open Loop Gain vs. Output Voltage Headroom vs. Power Supply.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.

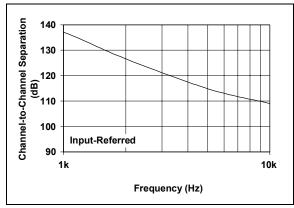


FIGURE 2-19: Channel to Channel Separation vs. Frequency (MCP6142 and MCP6144 only).

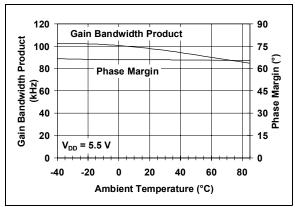


FIGURE 2-20: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature with $V_{DD} = 5.5V$.

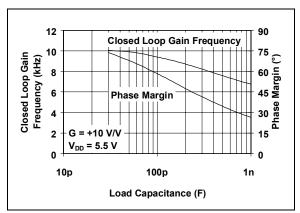


FIGURE 2-21: Closed Loop Gain Frequency, Phase Margin vs. Load Capacitance with $V_{DD} = 5.5V$.

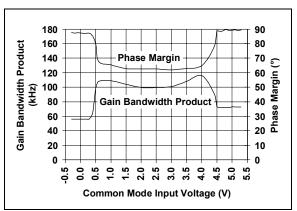


FIGURE 2-22: Gain Bandwidth Product, Phase Margin vs. Common Mode Input Voltage.

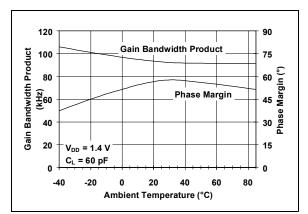


FIGURE 2-23: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature with $V_{DD} = 1.4V$.

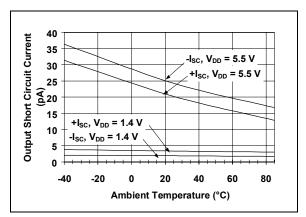
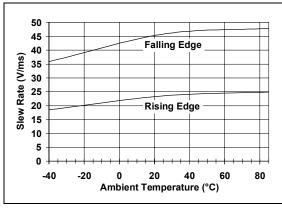
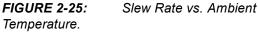


FIGURE 2-24: Output Short Circuit Current vs. Ambient Temperature vs. Power Supply Voltage.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.





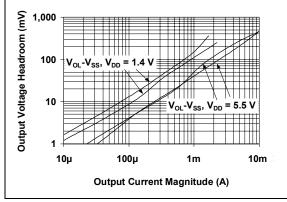


FIGURE 2-26: Output Voltage Headroom vs. Output Current Magnitude vs. Power Supply Voltage.

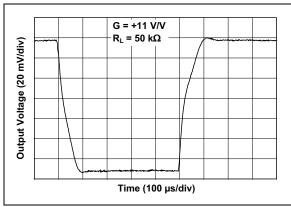


FIGURE 2-27: Small Signal Non-Inverting Pulse Response vs. Time.

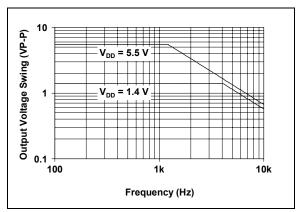


FIGURE 2-28: Output Voltage Swing vs. Frequency vs. Power Supply Voltage.

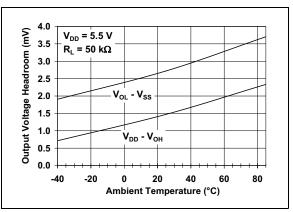


FIGURE 2-29: Output Voltage Headroom vs. Ambient Temperature with $V_{DD} = 5.5V$.

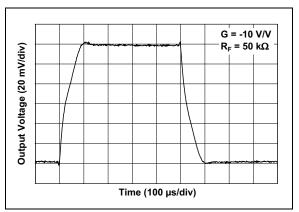


FIGURE 2-30: Small Signal Inverting Pulse Response vs. Time.

Note: Unless otherwise indicated, V_{DD} = +5V, V_{SS} = GND, T_A = 25°C, V_{CM} = $V_{DD}/2$, R_L = 1 M Ω to $V_{DD}/2$, C_L = 60 pF, and $V_{OUT} \sim V_{DD}/2$.

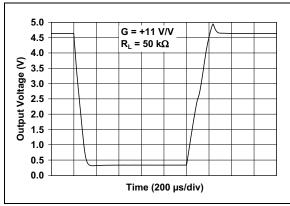


FIGURE 2-31: Large Signal Non-Inverting Pulse Response vs. Time.

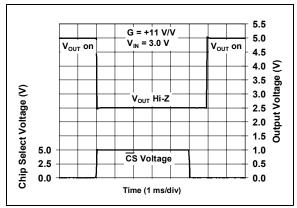


FIGURE 2-32: Chip Select (\overline{CS}) to Amplifier Output Response Time (MCP6143 only).

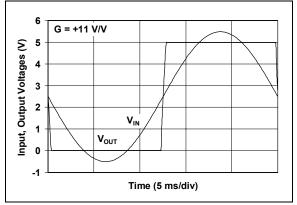


FIGURE 2-33: The MCP6141/2/3/4 family shows no phase reversal (for information only–the Maximum Absolute Input Voltage is still V_{SS} - 0.3V and V_{DD} + 0.3V).

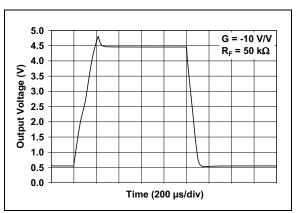


FIGURE 2-34: Large Signal Inverting Pulse Response vs. Time.

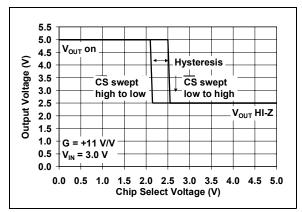


FIGURE 2-35: Output Voltage vs. Chip Select (CS) Voltage (MCP6143 only).

3.0 APPLICATIONS INFORMATION

The MCP6141/2/3/4 family of operational amplifiers are fabricated on Microchip's state-of-the-art CMOS process. They are stable for noise gain of 10 V/V or higher. Microchip also produces a unity gain stable product, the MCP6041/2/3/4 family, which has similar specifications. The MCP6041/2/3/4 family has a bandwidth of 1.4 kHz at a noise gain of 10 V/V, while the MCP6141/2/3/4 family has a bandwidth of 10 kHz at a noise gain of 10 V/V. These devices are suitable for a wide range of applications requiring very low power consumption. With these op amps, the power supply pin needs to be bypassed with a 0.1 μ F capacitor.

3.1 Rail-to-Rail Input

The input stage of these devices uses two differential input stages in parallel; one operates at low V_{CM} (common mode input voltage) and the other at high V_{CM}. With this topology, the MCP6141/2/3/4 family operates with V_{CM} up to 300 mV past either supply rail. The Input Offset Voltage is measured at both V_{CM} = V_{SS} - 0.3V and V_{DD} + 0.3V to ensure proper operation.

3.2 Output Loads and Battery Life

The MCP6141/2/3/4 op amp family has low quiescent current, which supports battery-powered applications. There is minimal quiescent current glitch when chip select (\overline{CS}) is raised or lowered. This prevents excessive current draw and reduced battery life when the part is turned off or on.

Heavy resistive loads at the output can cause excessive battery drain. Driving a DC voltage of 2.5V across a 100 k Ω load resistor will cause the supply current to increase by 25 μA , depleting the battery 43 times as fast as I_{\Omega} (0.6 μA typ) alone.

High frequency signals (fast edge rate) across capacitive loads will also significantly increase supply current. For instance, a 0.1 μF capacitor at the output presents an AC impedance of 15.9 k Ω (1/2 πfC) to a 100 Hz sinewave. It can be shown that the average power drawn from the battery by a 5.0 V_{p-p} sinewave (1.77 Vrms) under these conditions is:

EQUATION

$$\begin{split} P_{SUPPLY} &= (V_{DD} - V_{SS})(I_Q + V_{L(p-p)}fC_L) \\ &= (5V)(0.6\mu A + 5.0V_{p-p} \cdot 100Hz \cdot 0.1\mu F) \\ &= 3.0\mu W + 50\mu W \end{split}$$

This will drain the battery 18 times as fast as I_{Q} alone.

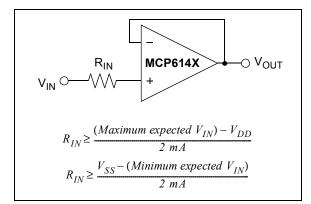
3.3 Rail-to-Rail Output

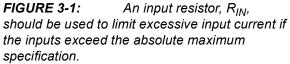
The MCP6141/2/3/4 family Maximum Output Voltage Swing defines the maximum swing possible under a particular output load. According to the specification table, the output can reach up to 10 mV of either supply rail with a 50 k Ω load.

3.4 Input Voltage and Phase Reversal

The MCP6141/2/3/4 op amp family uses CMOS transistors at the input. It is designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 2-33 shows an input voltage exceeding both supplies without output phase reversal.

The maximum operating V_{CM} that can be applied to the inputs is V_{SS} -0.3V and V_{DD} + 0.3V. Voltage on the input that exceeds this absolute maximum rating can cause excessive current to flow in or out of the input pins. Current beyond ±2 mA can cause possible reliability problems. Applications that exceed this rating must be externally limited with an input resistor, as shown in Figure 3-1.





3.5 Stability

The MCP6141/2/3/4 op amp family is designed to give high bandwidth and faster slew rate for circuits with high noise (G_n) or signal gain. The related unity-gain stable MCP6041/2/3/4 op amp family has lower AC performance, but it is preferable for low noise gain applications.

Noise gain is defined to be the gain from a voltage source at the non-inverting input to the output when all other voltage sources are zeroed (shorted out). Noise gain is independent of signal gain and depends only on components in the feedback loop.

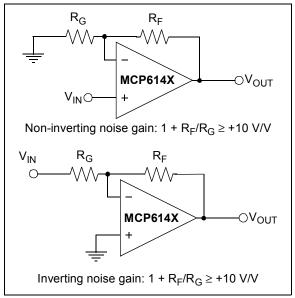


FIGURE 3-2: Noise gain for inverting and non-inverting amplifier configuration.

Figure 3-2 shows non-inverting and inverting amplifier circuits. In order for the amplifiers to be stable, the noise gain should meet the specified requirement:

EQUATION

$$G_n = 1 + \frac{R_F}{R_G} \ge 10V/V$$

Note that an inverting signal gain of G = -9 V/V corresponds to a noise gain G_n = +10 V/V.

Figure 3-3 shows a unity gain buffer and integrator that are unstable when used with the MCP6141/2/3/4 family. However, they are suitable for the MCP6041/2/3/4 family.

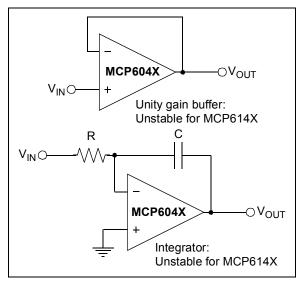


FIGURE 3-3: Typical Circuits that are not suitable for the MCP6141/2/3/4 family.

Note that the integrator circuit in Figure 3-3 becomes unity gain at high frequencies because of the capacitor. Therefore, this circuit is unstable for the MCP6141/2/3/4.

3.6 Capacitive Load and Stability

Driving capacitive loads can cause stability problems with voltage feedback op amps. Figure 2-21 shows how increasing the load capacitance will decrease the phase margin. While a phase margin above 60° is ideal, 45° is on the verge of instability. As can be seen, up to $C_L = 150 \text{ pF}$ can be placed on the MCP6141/2/3/4 op amp outputs without any problems, while 250 pF creates a 45° phase margin.

When the op amp is required to drive large capacitive loads ($C_L > 150 \text{ pF}$), a small series resistor (R_{ISO} in Figure 3-4) at the output of the amplifier improves the phase margin. This resistor makes the output load resistive at higher frequencies, which improves the phase margin. The bandwidth reduction caused by the capacitive load, however, is not changed. To select R_{ISO} , start with 1 k Ω , then use the MCP6141 SPICE macro model and bench testing to adjust R_{ISO} until there is a minimum frequency response peaking.

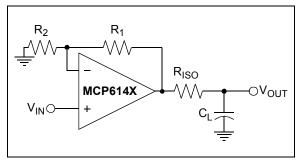


FIGURE 3-4: Amplifier circuit for heavy capacitive loads.

3.7 The MCP6143 Chip Select (CS) Option

The MCP6143 is a single amplifier with a chip select (CS) option. When CS is pulled high, the supply current drops to 20 pA (typ.) and goes through the CS pin to V_{SS} . When this happens, the amplifier is put into a high impedance state. By pulling CS low, the amplifier is enabled. If the CS pin is left floating, the amplifier will not operate properly. Figure 3-5 shows the output voltage and supply current response to a CS pulse.

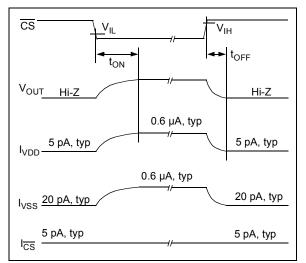


FIGURE 3-5: Timing Diagram for the \overline{CS} function on the MCP6143 op amp.

3.8 Layout Considerations

Good PC board layout techniques will help you achieve the performance shown in the specifications and typical performance curves. It will also assist in minimizing Electro-Magnetic Compatibility (EMC) issues.

3.8.1 SURFACE LEAKAGE

In applications where low input bias current is critical, PC board surface leakage effects and signal coupling from trace to trace need to be considered.

Surface leakage is caused by a difference in voltage between traces, combined with high humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the input current of the MCP6141/2/3/4 family at 25°C (1 pA, typ).

The simplest technique to reduce surface leakage is using a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin or trace. Figure 3-6 shows an example of a typical layout.

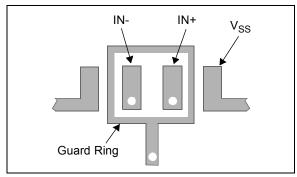


FIGURE 3-6: Example of Guard Ring layout.

Circuit schematics for different guard ring implementations are shown in Figure 3-7. Figure 3-7A biases the guard ring to the input common mode voltage, which is most effective for non-inverting gains. Figure 3-7B biases the guard ring to a reference voltage (V_{REF} , which can be ground), which is useful for inverting gains and precision photo sensing circuits.

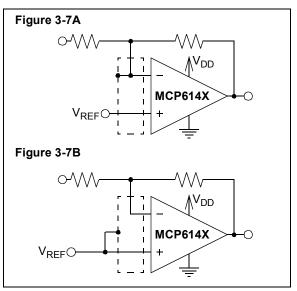


FIGURE 3-7: Two possible guard ring connection strategies to reduce surface leakage effects.

3.8.2 COMPONENT PLACEMENT

In order to help prevent crosstalk:

- Separate digital components from analog components, and low speed devices from high speed devices.
- Keep sensitive traces short and straight. Separate them from interfering components and traces. This is especially important for high frequency (low rise time) signals.
- Use a 0.1 μF supply bypass capacitor within 0.1" (2.5 mm) of the V_{DD} pin. It must connect directly to the ground plane.

3.8.3 SIGNAL COUPLING

The input pins of the MCP6141/2/3/4 family of op amps are high impedance, which allows noise injection. This noise can be capacitively or magnetically coupled. In either case, using a ground plane helps reduce noise injection.

When noise is coupled capacitively, the ground plane provides shunt capacitance to ground for high frequency signals (Figure 3-8 shows the equivalent circuit). The coupled current, I_M , produces a lower voltage ($V_{TRACE 2}$) on the victim trace when the trace to ground plane capacitance (C_{SH2}) is large and the terminating resistor (R_{T2}) is small. Increasing the distance between traces and using wider traces also helps.

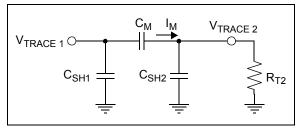


FIGURE 3-8: Equivalent circuit for capacitive coupling between traces on a PC board (with ground plane).

When noise is coupled magnetically, the ground plane reduces the mutual inductance between traces. This occurs because the ground return current at high frequencies will follow a path directly beneath the signal trace. Increasing the separation between traces makes a significant difference. Changing the direction of one of the traces can also reduce magnetic coupling.

If these techniques are not enough, it may help to place guard traces next to the victim trace. They should be on both sides of the victim trace and be as close as possible. Connect the guard traces to ground plane at both ends and in the middle for long traces.

3.9 Typical Applications

3.9.1 BATTERY CURRENT SENSING

The MCP6141/2/3/4 op amps' Common Mode Input Range, which goes 300 mV beyond both supply rails, supports their use in high side and low side battery current sensing applications. The very low quiescent current (0.6 μ A, typ.) help prolong battery life, while the rail-to-rail output allows you to detect low currents.

Figure 3-9 shows a high side battery current sensor circuit. The feedback and input resistors are sized to minimize power losses. The battery current (I_{DD}) through the 1 k Ω resistor causes its top terminal to be more negative than the bottom terminal. This keeps the common mode input voltage of the op amp \leq V_{DD}, which is within its allowed range. The output of the op amp can reach V_{DD} - 0.1 mV (see Figure 2-26), which is a smaller error than the offset voltage.

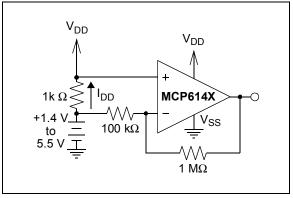


FIGURE 3-9: High Side Battery Current Sensor.

3.9.2 SUMMING AMPLIFIER

The rail-to-rail input and output, the 600 nA (typ.) quiescent current and the wide bandwidth make the MCP6141/2/3/4 family of operational amplifiers fit well in a summing amplifier circuit, as shown in Figure 3-10.

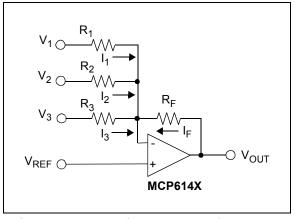


FIGURE 3-10: Summing amplifier circuit.

In this configuration, the amplifier outputs the sum of the three input voltages. The ratio of the sum and the output voltage is defined using the feedback and input resistors. V_{REF} is used to offset the output voltage. This family of amplifiers is stable for noise gain (G_n) of 10 V/V or higher. The G_n and the signal gain of the summing amplifier is calculated as shown below:

EQUATION

Noise Gain:
$G_n = 1 + R_F \left(\frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right) \ge 10 \ V/V$
Signal Gain:
$V_{0I} = \frac{-R_F}{R_I} \times V_I$
$V_{02} = \frac{-R_F}{R_2} \times V_2$
$V_{03} = \frac{-R_F}{R_3} \times V_3$
$V_{04} = \left(I + \frac{R_F}{R_I} + \frac{R_F}{R_2} + \frac{R_F}{R_3}\right) \times V_{REF}$
$V_{OUT} = V_{01} + V_{02} + V_{03} + V_{04}$
$V_{OUT} = R_F \left[\frac{V_{REF} - V_I}{R_I} + \frac{V_{REF} - V_2}{R_2} + \frac{V_{REF} - V_3}{R_3} \right] + V_{REF}$

At a noise gain of 10 V/V, the amplifier bandwidth is approximately 10 kHz. The bandwidth to quiescent current ratio of MCP6141/2/3/4 makes this device an appropriate choice for battery-powered applications.

4.0 SPICE MACRO MODEL

The Spice macro model for the MCP6141, MCP6142, MCP6143 and MCP6144 simulates the typical amplifier performance of offset voltage, DC power supply rejection, input capacitance, DC common mode rejection, open loop gain over frequency, phase margin, output swing, DC power supply current, power supply current change with supply voltage, input common mode range, output voltage range vs. load and input voltage noise.

The characteristics of the MCP6141, MCP6142, MCP6143 and MCP6144 amplifiers are similar in terms of performance and behavior. This single op amp macro model supports all four devices, with the exception of the chip select function of the MCP6143, which is not modeled.

The listing for this macro model is shown on the next page. The most recent revision of the model can be downloaded from Microchip's web site at <u>www.microchip.com</u>.

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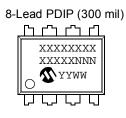
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```
.SUBCKT MCP6141 1 2 3 4 5
                | | Output
                  | | Negative Supply
                 | Positive Supply
                | Inverting Input
               Non-inverting Input
* Macromodel for the MCP6141/2/3/4 op amp family:
   MCP6141 (single)
   MCP6142 (dual)
   MCP6143 (single w/ CS; chip select is not modeled)
   MCP6144 (quad)
* Revision History:
   REV A: 06-Sep-02, KEB (created model)
* Recommendations:
   Use PSPICE (or SPICE 2G6; other simulators may require translation)
   For a quick, effective design, use a combination of: data sheet
     specs, bench testing, and simulations with this macromodel
   For high impedance circuits, set GMIN=100F in the .OPTIONS
     statement
* Supported:
   Typical performance at room temperature (25 degrees C)
   DC, AC, Transient, and Noise analyses.
   Most specs, including: offsets, DC PSRR, DC CMRR, input impedance,
     open loop gain, voltage ranges, supply current, ..., etc.
* Not Supported:
   Chip select (MCP6143)
    Variation in specs vs. Power Supply Voltage
    Distortion (detailed non-linear behavior)
   Temperature analysis
   Process variation
   Behavior outside normal operating region
* Input Stage
V10 3 10 -300M
R10 10 11 258K
R11 10 12 258K
C11 11 12 3.53P
C12 1 0 6.00P
E12 1 14 POLY(4) 20 0 21 0 26 0 27 0 1.00M 117 117 1 1
I12 14 0 1.50P
M12 11 14 15 15 NMI L=2.00U W=5.00U
C13 14 2 6.00P
M14 12 2 15 15 NMI L=2.00U W=5.00U
I14 2 0 500E-15
C14 2 0 6.00P
```

I15 15 4 300N V16 16 4 200M D16 16 15 DL V13 3 13 50.0M D13 14 13 DL * Noise, PSRR, and CMRR I20 21 20 423U D20 20 0 DN1 D21 0 21 DN1 G26 0 26 POLY(1) 3 4 308U -56.0U R26 26 0 1 G27 0 27 POLY(2) 1 3 2 4 -979U 178U 178U R27 27 0 1 * Open Loop Gain, Slew Rate G30 0 30 POLY(1) 12 11 0 1.00K R30 30 0 1 E31 31 0 POLY(1) 3 4 29.3 1.05 D31 30 31 DL E32 0 32 POLY(1) 3 4 57.0 2.04 D32 32 30 DL G33 0 33 POLY(1) 30 0 0 562 R33 33 0 1 C33 33 0 838M G34 0 34 POLY(1) 33 0 0 1.00 R34 34 0 1.00 C34 34 0 8.53U G35 0 35 POLY(2) 34 0 33 34 0 1.00 1.22 R35 35 0 1.00 * Output Stage G50 0 50 POLY(1) 57 5 0 1.00 D51 50 51 DL R51 51 0 1K D52 52 50 DL R52 52 0 1K G53 3 0 POLY(1) 51 0 300N 1M G54 0 4 POLY(1) 52 0 300N -1M E55 55 0 POLY(2) 3 0 51 0 -10M 1 -100M D55 57 55 DLS E56 56 0 POLY(2) 4 0 52 0 10M 1 -100M D56 56 57 DLS G57 0 57 POLY(3) 3 0 4 0 35 0 0 17.8U 17.8U 35.5U R57 57 0 28.2K R58 57 5 1.00 C58 5 0 2.00P * Models .MODEL NMI NMOS .MODEL DL D N=1 IS=1F .MODEL DLS D N=10M IS=1F .MODEL DN1 D IS=1F KF=1.17E-18 AF=1 .ENDS MCP6141

5.0 PACKAGING INFORMATION

5.1 Package Marking Information

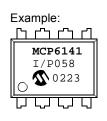


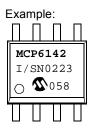
8-Lead SOIC (150 mil)



8-Lead MSOP







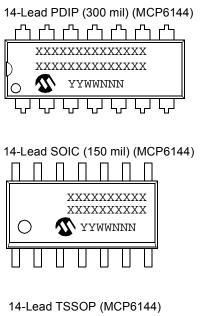
Example:

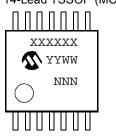


Legend	XXX YY WW NNN	Customer specific information* Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code					
	Note : In the event the full Microchip part number cannot be marked on one line, it wi be carried over to the next line thus limiting the number of available characters for customer specific information.						

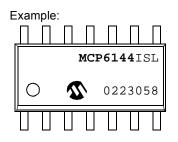
* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

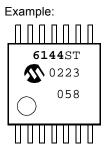
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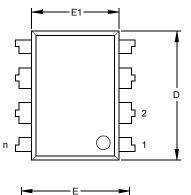


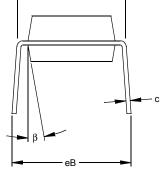
Example: MCP6144-I/P 0223058 UUUUUUUUU

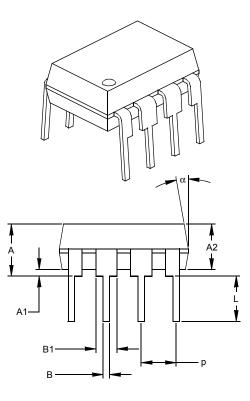




8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)







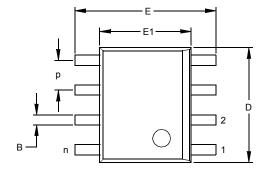
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Dimensior	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

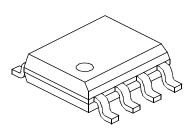
* Controlling Parameter § Significant Characteristic

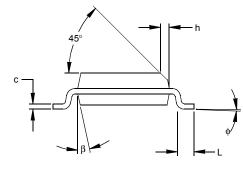
Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

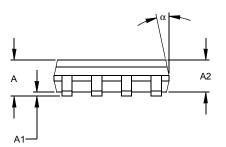
.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)









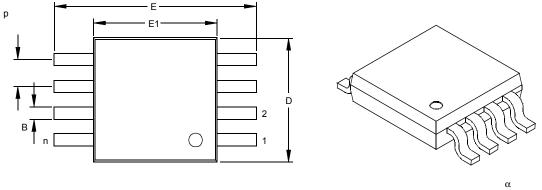
	Units		INCHES*		N	IILLIMETERS	5
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	А	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

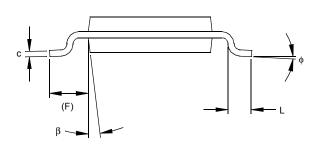
* Controlling Parameter § Significant Characteristic

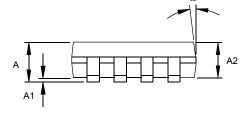
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

8-Lead Plastic Micro Small Outline Package (MS) (MSOP)







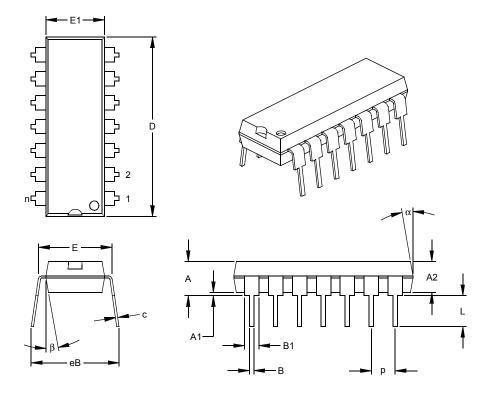
Units		INCHES		М	ILLIMETERS*	
on Limits	MIN	NOM	MAX	MIN	NOM	MAX
n		8				8
р	.026			0.65		
А			.044			1.18
A2	.030	.034	.038	0.76	0.86	0.97
A1	.002		.006	0.05		0.15
E	.184	.193	.200	4.67	4.90	.5.08
E1	.114	.118	.122	2.90	3.00	3.10
D	.114	.118	.122	2.90	3.00	3.10
L	.016	.022	.028	0.40	0.55	0.70
F	.035	.037	.039	0.90	0.95	1.00
¢	0		6	0		6
С	.004	.006	.008	0.10	0.15	0.20
В	.010	.012	.016	0.25	0.30	0.40
α		7			7	
β		7			7	
	n n p A A2 A1 E E1 D L F \$\phi\$ C B \$\alpha\$	on Limits MIN n P A A A2 .030 A1 .002 E .184 E1 .114 D .114 L .016 F .035 φ 0 C .004 B .010 α	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

*Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. Drawing No. C04-111

14-Lead Plastic Dual In-line (P) – 300 mil (PDIP)



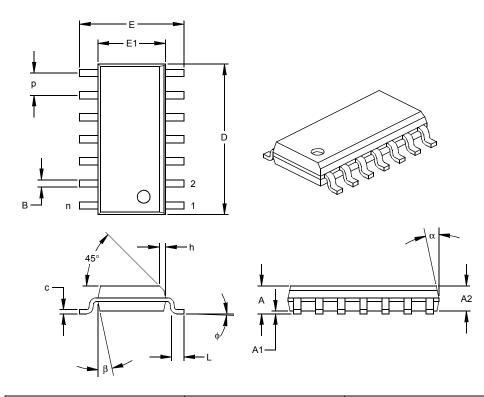
s MIN .140 .115	NOM 14 .100 .155	MAX	MIN	NOM 14	MAX
	.100			14	
	155			2.54	
115	.100	.170	3.56	3.94	4.32
.115	.130	.145	2.92	3.30	3.68
.015			0.38		
.300	.313	.325	7.62	7.94	8.26
.240	.250	.260	6.10	6.35	6.60
.740	.750	.760	18.80	19.05	19.30
.125	.130	.135	3.18	3.30	3.43
.008	.012	.015	0.20	0.29	0.38
.045	.058	.070	1.14	1.46	1.78
.014	.018	.022	0.36	0.46	0.56
.310	.370	.430	7.87	9.40	10.92
5	10	15	5	10	15
5	10	15	5	10	15
	.240 .740 .125 .008 .045 .014 .310	.240 .250 .740 .750 .125 .130 .008 .012 .045 .058 .014 .018 .310 .370 5 10	.240 .250 .260 .740 .750 .760 .125 .130 .135 .008 .012 .015 .045 .058 .070 .014 .018 .022 .310 .370 .430 5 10 15	.240 .250 .260 6.10 .740 .750 .760 18.80 .125 .130 .135 3.18 .008 .012 .015 0.20 .045 .058 .070 1.14 .014 .018 .022 0.36 .310 .370 .430 7.87 5 10 15 5	.240 .250 .260 6.10 6.35 .740 .750 .760 18.80 19.05 .125 .130 .135 3.18 3.30 .008 .012 .015 0.20 0.29 .045 .058 .070 1.14 1.46 .014 .018 .022 0.36 0.46 .310 .370 .430 7.87 9.40 5 10 15 5 10

* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-005

14-Lead Plastic Small Outline (SL) - Narrow, 150 mil (SOIC)



	Units	INCHES*			MILLIMETERS		
Dimens	sion Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.236	.244	5.79	5.99	6.20
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99
Overall Length	D	.337	.342	.347	8.56	8.69	8.81
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	¢	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15
* Controlling Parameter							

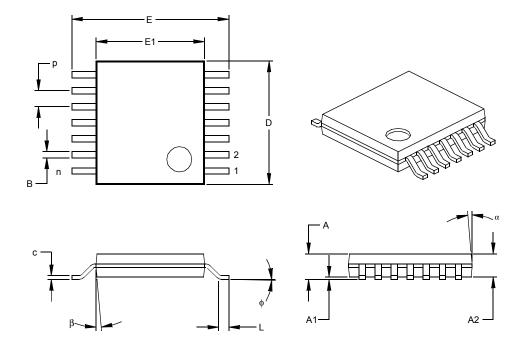
* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



Units		INCHES			MILLIMETERS*		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.026			0.65	
Overall Height	А			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-087

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PART NO.	<u>x /xx</u>	Examples:
Device	Temperature Package Range	 a) MCP6141-I/P: Industrial temperature, PDIP package.
Device:	MCP6141: CMOS Single Op Amp MCP6141T: CMOS Single Op Amp (Tape and Reel for SOIC, MSOP) MCP6142: CMOS Dual Op Amp MCP6142T: CMOS Dual Op Amp (Tape and Reel for SOIC and TSSOP) MCP6143: CMOS Single Op Amp w/CS Function MCP6143: CMOS Single Op Amp w/CS Function (Tape and Reel for SOIC and MSOP) MCP6144: CMOS Quad Op Amp MCP6144: CMOS Quad Op Amp MCP6144: CMOS Quad Op Amp MCP6144T: CMOS Quad Op Amp MCP6144T: CMOS Quad Op Amp MCP6144T: CMOS Quad Op Amp	 b) MCP6141T-I/SN: Tape and Reel, Industrial temperature, SOIC package. a) MCP6142-I/SN: Industrial temperature, SOIC package. b) MCP6142-I/MS: Industrial temperature, MSOP package. a) MCP6143-I/MS: Industrial temperature, MSOP package. b) MCP6143-I/P: Industrial temperature, PDIP package.
Temperature Range:	$I = -40^{\circ}C \text{ to } +85^{\circ}C$	a) MCP6144-I/SL: Industrial temperature, SIOC package.
Package:	MS = Plastic MSOP, 8-lead P = Plastic DIP (300 mil Body), 8-lead, 14-lead SN = Plastic SOIC (150 mil Body), 8-lead SL = Plastic SOIC (150 mil Body), 14-lead ST = Plastic TSSOP (4.4mm Body), 14-lead	b) MCP6144T-I/ST: Tape and Reel, Indus- trial temperature, TSSOP package.

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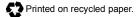
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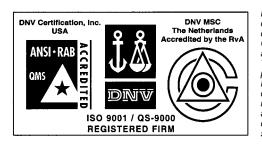
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